

STTH120L04TV1

Ultrafast high voltage rectifier

Mian product characteristics

I _{F(AV)}	2 x 60 A
V _{RRM}	400 V
T _j (max)	150° C
V _F (typ)	0.83 V
t _{rr} (max)	50 ns

Features and benefits

- Ultrafast switching
- Low reverse current
- Low thermal resistance
- Reduces switching and conduction losses
- Package insulation voltage: 2500 V_{RMS}

Description

The STTH120L04TV1 uses ST 400 V technology and is specially suited for use in switching power supplies, welding equipment, and industrial applications, as an output rectification diode.

$A1 \longrightarrow K1$ $A2 \longrightarrow K2$ $K1$ $K2$ $K1$ $K2$ $A1$	
ISOTOP STTH120L04TV1	

Order codes

Part number	Marking
STTH120L04TV1	STTH120L04TV1

Table 1. Absolute ratings (limiting values, per diode)

Symbol	Parar	Value	Unit		
V _{RRM}	Repetitive peak reverse voltage			400	V
I _{F(RMS)}	RMS forward current			120	А
I _{F(AV)}	Average forward current	$T_c = 115^\circ C \delta = 0.5$ Per diode		60	А
I _{FSM}	Surge non repetitive forward current	600	А		
T _{stg}	Storage temperature range	-55 to + 150	°C		
Тj	Maximum operating junction temperature			150	°C

1 Characteristics

Table 2. Thermal resistance	Table	2.	Thermal	resistance
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Symbol	Parameter	Value (max).	Unit	
Р	lunction to copp	Per diode	0.74	
R _{th(j-c)} Junction to case		Total	0.42	°C/W
R _{th(c)}	Coupling		0.1	

When diodes 1 and 2 are used simultaneously:

 Δ Tj(diode 1) = P(diode 1) x R_{th(j-c)}(Per diode) + P(diode 2) x R_{th(c)}

 Table 3.
 Static electrical characteristics (per diode)

Symbol	Parameter	Test conditions		Min.	Тур	Max.	Unit
I _B ⁽¹⁾	Reverse leakage	$T_j = 25^\circ C$	V V			50	μA
'R`´	current	$T_j = 125^\circ C$ $V_R = V_{RRM}$		50	500	μΑ	
V _F ⁽²⁾	$T_j = 25^{\circ} C$		I 60 A			1.2	V
V _F ⁽²⁾ Forv	Forward voltage drop	T _j = 150° C	I _F = 60 A		0.83	1.0	V

1. Pulse test: $t_p = 5 \text{ ms}, \delta < 2\%$

2. Pulse test: $t_p = 380 \ \mu s, \ \delta < 2\%$

To evaluate the conduction losses use the following equation:

 $P = 0.8 \text{ x } I_{F(AV)} + 0.0033 I_{F^{2}(RMS)}$

Symbol	Parameter	Test conditions			Тур	Max	Unit
+	t_{rr} Reverse recovery $T_j = 25^{\circ} C$		$I_F = 1 A dI_F/dt = 50 A/\mu s$ $V_R = 30 V$		66	90	ns
۲rr			$I_F = 1 A dI_F/dt = 200 A/\mu s$ $V_R = 30 V$		36	50	115
I _{RM}	ourront		I _F = 60 A V _R = 200 V dI _F /dt = 100 A/μs			15	A
S _{factor}	Softness factor	$T_j = 125^\circ C$	I _F = 60 A V _R = 200 V dI _F /dt = 100 A/μs		0.4		
t _{fr}	Forward recovery time	$T_j = 25^\circ C$	$I_{F} = 60 \text{ A} \qquad dI_{F}/dt = 200 \text{ A}/\mu\text{s}$ $V_{FR} = 1.1 \text{ x} \text{ V}_{Fmax}$			600	ns
V _{FP}	Forward recovery voltage	$T_j = 25^\circ C$	$I_{F} = 60 \text{ A} dI_{F}/dt = 200 \text{ A}/\mu\text{s}$ $V_{FR} = 1.1 \text{ x} \text{ V}_{Fmax}$		2.6		V

T.=25°C

1.4

1.6

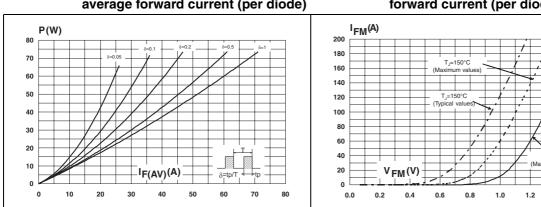


Figure 3. Relative variation of thermal impedance junction to case versus pulse duration

Peak reverse recovery current versus dl_⊧/dt (typical values, per diode)

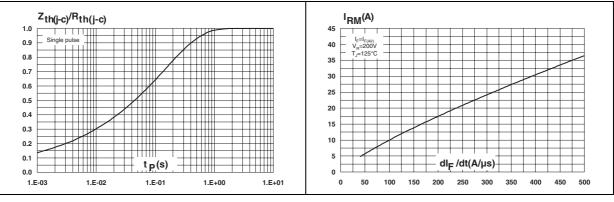


Figure 4.

Figure 5. Reverse recovery time versus dI_{F}/dt (typical values, per diode)

Figure 6. Reverse recovery charges versus dl_F/dt (typical values, per diode)

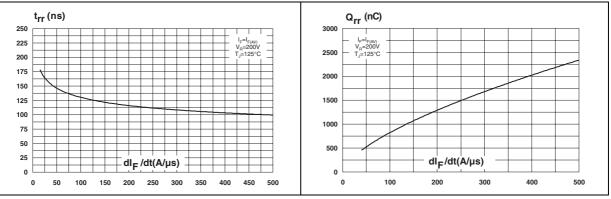


Figure 1. Conduction losses versus average forward current (per diode)

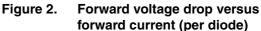


Figure 7. Reverse recovery softness factor versus dl_F/dt (typical values, per diode)

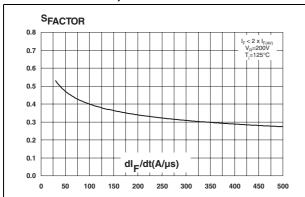
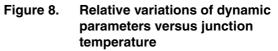


Figure 9. Transient peak forward voltage versus dl_F/dt (typical values, per diode)



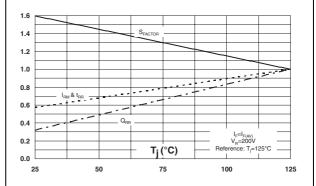


Figure 10. Forward recovery time versus dl_F/dt (typical values, per diode)

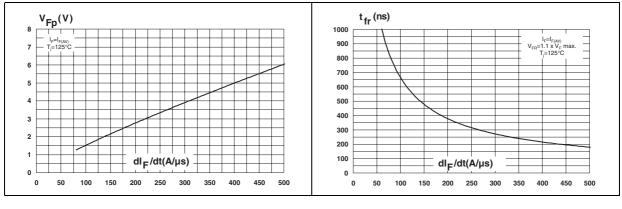
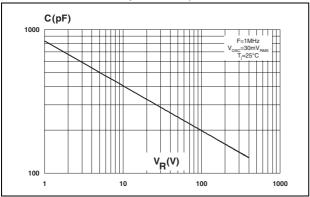


Figure 11. Junction capacitance versus reverse voltage applied (typical values, per diode)

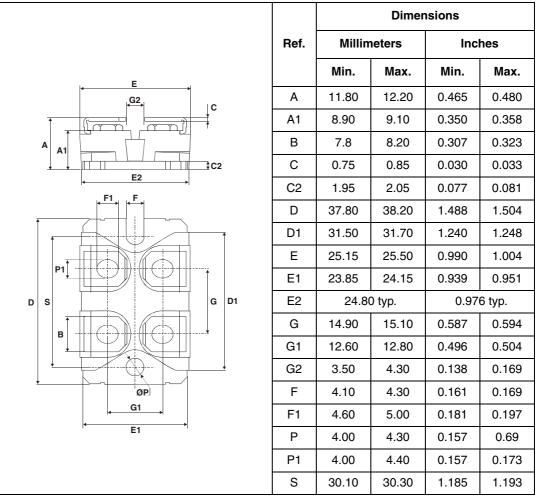




2 Package information

- Epoxy meets UL94, V0
- Cooling method: by conduction (C)

Table 5. ISOTOP Dimensions



In order to meet environmental requirements, ST offers these devices in ECOPACK® packages. These packages have a lead-free second level interconnect. The category of second level interconnect is marked on the package and on the inner box label, in compliance with JEDEC Standard JESD97. The maximum ratings related to soldering conditions are also marked on the inner box label. ECOPACK is an ST trademark. ECOPACK specifications are available at: www.st.com.

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3 Ordering information

Ordering type	Marking	Package	Weight	Base qty	Delivery mode
STTH120L04TV1	STTH120L04TV1	ISOTOP	27 g (without screws)	10 (with screws)	Tube

4 Revision history

Date	Revision	Description of Changes
11-Aug-2006	1	First issue



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